

IN THE CLAIMS

Please amend the claims as follows:

Claim 1 (Currently Amended): A plasma processing apparatus comprising:
a process vessel in which a substrate is processed;
a gas introducing part that introduces process gas into said process vessel;
a transmissive window including a dielectric to airtightly cover an upper opening of the process vessel;
an antenna member, located above the transmissive window, that introduces a microwave into the process vessel;
a support part supporting a peripheral edge portion of said transmissive window; and
an exhaust pipe that exhausts an atmosphere in the process vessel via an exhaust device,
wherein said transmissive window has, in a center area thereof, a hanging portion made of a same material as a material of said transmissive window, and a gap with a predetermined distance or more is formed between an outer peripheral surface of the hanging portion and a sidewall of said support part,
wherein L/D is equal to 3 or more, where L is a vertical length of the hanging portion and D is the predetermined distance, D being set to 0.5 to 10 mm so that a contact point between the support part and the transmissive window is not in direct sight from the substrate, and
wherein the gap extends over an entirety of the vertical length such that there is a uniform gap width.

Claim 2 (Canceled)

Claim 3 (Original): The plasma processing apparatus according to claim 1, wherein the predetermined distance is 0.5 to 5 mm.

Claim 4 (Canceled)

Claim 5 (Original): The plasma processing apparatus according to claim 1, wherein a recessed portion is formed in a center side area of the hanging portion.

Claim 6 (Original): The plasma processing apparatus according to claim 5, wherein a sidewall forming the recessed portion is a tapered surface inclining toward a center side of the recessed portion.

Claim 7 (Original): The plasma processing apparatus according to claim 5, wherein a width of the hanging portion is $\lambda/4$ or less, where λ is a wavelength of the microwave in said transmissive window.

Claim 8 (Canceled)

Claim 9 (Previously Presented): The plasma processing apparatus according to claim 1, wherein the vertical length of the hanging portion is 20 mm or more.

Claim 10 (Previously Presented): The plasma processing apparatus according to claim 1, wherein at least one surface, in said support part or the sidewall continuing from said support part, facing an inside of said process vessel is coated with Y_2O_3 (yttria).

Claim 11 (Currently Amended): A plasma processing apparatus comprising:

- a process vessel in which a substrate is processed;
- a gas introducing part that introduces process gas into said process vessel;
- a transmissive window including a dielectric to airtightly cover an upper opening of the process vessel;
- an antenna member, located above the transmissive window, that introduces a microwave into the process vessel;
- a support part supporting a peripheral edge portion of said transmissive window; and
- an exhaust pipe that exhausts an atmosphere in the process vessel via an exhaust device,

wherein under said support part, an eave portion projecting from a sidewall of the process vessel toward an interior of the process vessel is separate from a contact point between the support part and a lower surface of said transmissive window by a predetermined distance or more on an entire surface in a circumferential direction, and

wherein the predetermined distance is set to 0.5 to 10 mm so that the contact point between the support part and the transmissive window is not in direct sight from the substrate.

Claim 12 (Canceled)

Claim 13 (Original): The plasma processing apparatus according to claim 11, wherein the predetermined distance is 0.5 to 5 mm.

Claim 14 (Withdrawn): A plasma processing method using a plasma processing apparatus that processes a substrate in a process vessel by plasma generated by supply of a

microwave, the plasma processing apparatus comprising: a transmissive window made of a dielectric to airtightly cover an upper opening of the process vessel; and a support part supporting, in the process vessel, a peripheral edge portion of the transmissive window, wherein the transmissive window has, in a center area thereof, a hanging portion made of a same material as a material of the transmissive window, and a gap is formed between an outer peripheral surface of the hanging portion and a sidewall inner surface of the process vessel continuing from the support part, and the method comprising
adjusting size of the gap to control strength of an electric field in a peripheral portion of the transmissive window.

Claim 15 (Withdrawn): The plasma processing method according to claim 14,
wherein the outer peripheral surface of the hanging portion is a tapered surface with the gap gradually becoming larger toward a lower side, and
wherein the strength of the electric field in the peripheral portion of the transmissive window is controlled by adjusting a taper angle of the tapered surface instead of adjusting the size of the gap.

Claim 16 (Previously Presented): The plasma processing apparatus according to claim 1, wherein corner portions on a boundary between the outer peripheral surface of the hanging portion and a portion, in the transmissive window, supported by the support part, and corner portions on a boundary between the outer peripheral surface of the hanging portion and a lower surface of the hanging portion, have a curved surface shape.